NSN 5962-01-360-1358

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View Online at https://aerobasegroup.com/nsn/5962-01-360-1358 **Body Length:** 1.110 inches **Body Width:** Between 0.245 inches and 0.310 inches **Body Height:** Between 0.245 inches and 0.310 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Burn in and electrostatic sensitive and monolithic and programmed **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 14 input **Current Rating Per Characteristic:** 50.00 milliamperes forward current, peak total value not applicable **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 0.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 35.00 nanoseconds access **Memory Device Type:** Ram **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

22 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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